TP3069

"Enhanced" Serial Interface CMOS CODEC/Filter COMBO®

General Description

The TP3069 (A-law) is a monolithic PCM CODEC/Filter utilizing the A/D and D/A conversion architecture shown in *Figure 1*, and a serial PCM interface. The device is fabricated using National's advanced double-poly CMOS process (microCMOS).

Similar to the TP305X family, this device features an additional Receive Power Amplifier to provide push-pull balanced output drive capability. The receive gain can be adjusted by means of two external resistors for an output level of up to $\pm 6.6 V$ across a balanced 600Ω load.

Also included is an Analog Loopback switch and a $\overline{\text{TS}_X}$ output.

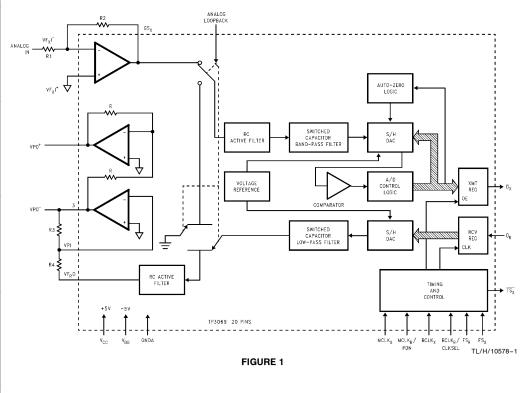
Note: See also AN-370, "Techniques for Designing with CODEC/Filter COMBO Circuits."

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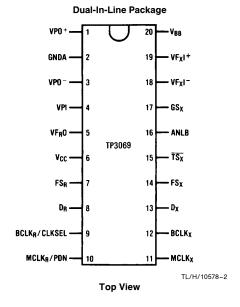
Features

- Complete CODEC and filtering system including:
 - Transmit high-pass and low-pass filtering
 - Receive low-pass filter with sin x/x correction
 - Active RC noise filters
 - A-law compatible COder and DECoder
 - Internal precision voltage reference
 - Serial I/O interface
 - Internal auto-zero circuitry
 - Receive push-pull power amplifiers
- Designed for D3/D4 and CCITT applications
- ±5V operation
- Low operating power—typically 70 mW
- Power-down standby mode—typically 3 mW
- Automatic power-down
- TTL or CMOS compatible digital interfaces
- Maximizes line interface card circuit density

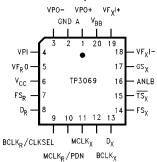
Block Diagram



Connection Diagrams



Plastic Chip Carrier



Top View

TL/H/10578-3

Order Number TP3069J See NS Package Number J20A

Order Number TP3069N See NS Package Number N20A

Order Number TP3069V See NS Package Number V20A

Order Number TP3069WM See NS Package Number M20B

Pin Description

Symbol	Function	Symbol	Function
VPO+	The non-inverted output of the receive power amplifier.	MCLK _X	Transmit master clock. Must be 1.536 MHz, 1.544 MHz or 2.048 MHz. May be asynchronous with MCLK _B . Best
GNDA	Analog ground. All signals are referenced to this pin.		performance is realized from synchronous operation.
VPO-	The inverted output of the receive power amplifier.	BCLK _X	The bit clock which shifts out the PCM data on D_X . May vary from 64 kHz to 2.048 MHz,
VPI	Inverting input to the receive power amplifier.		but must be synchronous with MCLKX.
VF _R O V _{CC}	Analog output of the receive filter. Positive power supply pin. $V_{CC} = +5V \pm 5\%$.	D_X	The TRI-STATE® PCM data output which is enabled by FSx.
FS _R	Receive frame sync pulse which enables BCLK _R to shift PCM data into D _R . FS _R is an 8 kHz pulse train. See <i>Figures 2</i> and <i>3</i> for timing details.	FS _X	Transmit frame sync pulse input which enables $BCLK_X$ to shift out the PCM data on D_X . FS_X is an 8 kHz pulse train, see <i>Figures 2</i> and <i>3</i> for timing details.
D _R	Receive data input. PCM data is shifted into D_R following the FS $_R$ leading edge.	TS _X	Open drain output which pulses low during the encoder time slot.
BCLK _R / CLKSEL	The bit clock which shifts data into D _R after the FS _R leading edge. May vary from 64 kHz to 2.048 MHz. Alternatively, may be a logic input which selects either 1.536 MHz/1.544 MHz or 2.048 MHz for master clock in synchronous mode and BCLK _X is used for both transmit and receive directions (see Table I).	ANLB	Analog Loopback control input. Must be set to logic '0' for normal operation. When pulled to logic '1', the transmit filter input is disconnected from the output of the transmit preamplifier and connected to the output of the receive switched capacitor low-pass filter and the input to the receive RC active filter is connected to ground. This results in the VFRO output being at ground level during
MCLK _R / PDN	Receive master clock. Must be 1.536 MHz, 1.544 MHz or 2.048 MHz. May be		analog loopback operation.
	asynchronous with MCLK _X , but should be synchronous with MCLK _X for best	GS _X	Analog output of the transmit input amplifier. Used to externally set gain.
	performance. When MCLK _R is connected	VF_XI^-	Inverting input of the transmit input amplifier.
	continuously low, $\mathrm{MCLK}_{\mathrm{X}}$ is selected for all internal timing. When $\mathrm{MCLK}_{\mathrm{R}}$ is connected	VF _X I+	Non-inverting input of the transmit input amplifier.
	continuously high, the device is powered down.	V_{BB}	Negative power supply pin. $V_{BB} = -5V \pm 5\%$

Functional Description

POWER-UP

When power is first applied, power-on reset circuitry initializes the COMBOTM and places it into a power-down state. All non-essential circuits are deactivated and the D_X , VF_RO , VPO^- and VPO^+ outputs are put in high impedance states. To power-up the device, a logical low level or clock must be applied to the MCLKR/PDN pin and FS_X and/or FS_R pulses must be present. Thus, 2 power-down control modes are available. The first is to pull the MCLKR/PDN pin high; the alternative is to hold both FS_X and FS_R inputs continuously low—the device will power-down approximately 1 ms after the last FS_X or FS_R pulse. Power-up will occur on the first FS_X or FS_R pulse. The TRI-STATE PCM data output, D_X, will remain in the high impedance state until the second FS_X pulse.

SYNCHRONOUS OPERATION

For synchronous operation, the same master clock and bit clock should be used for both the transmit and receive directions. In this mode, a clock must be applied to MCLK_X and the MCLK_R/PDN pin can be used as a power-down control. A low level on MCLK_R/PDN powers up the device and a high level powers down the device. In either case, MCLK_X will be selected as the master clock for both the transmit and receive circuits. A bit clock must also be applied to BCLK_X and the BCLK_R/CLKSEL can be used to select the proper internal divider for a master clock of 1.536 MHz, 1.544 MHz or 2.048 MHz. For 1.544 MHz operation, the device automatically compensates for the 193rd clock pulse each frame.

With a fixed level on the BCLK $_{\rm R}$ /CLKSEL pin, BLCK $_{\rm X}$ will be selected as the bit clock for both the transmit and receive directions. Table I indicates the frequencies of operation which can be selected, depending on the state of BCLK $_{\rm R}$ /CLKSEL. In this synchronous mode, the bit clock, BCLK $_{\rm X}$, may be from 64 kHz to 2.048 MHz, but must be synchronous with MCLK $_{\rm X}$.

Each FS $_{\rm X}$ pulse begins the encoding cycle and the PCM data from the previous encode cycle is shifted out of the enabled D $_{\rm X}$ output on the positive edge of BCLK $_{\rm X}$. After 8-bit clock periods, the TRI-STATE D $_{\rm X}$ output is returned to a high impedance state. With an FS $_{\rm R}$ pulse, PCM data is latched via the D $_{\rm R}$ input on the negative edge of BCLK $_{\rm X}$ (or BCLK $_{\rm R}$ if running). FS $_{\rm X}$ and FS $_{\rm R}$ must be synchronous with MCLK $_{\rm X/R}$.

TABLE I. Selection of Master Clock Frequencies

BCLK _R /CLKSEL	Master Clock Frequency Selected						
DOLKH/OLKSLL	TP3069						
Clocked	2.048 MHz						
0	1.536 MHz or 1.544 MHz						
1	2.048 MHz						

ASYNCHRONOUS OPERATION

For asynchronous operation, separate transmit and receive clocks may be applied. $\rm MCLK_X$ and $\rm MCLK_R$ must be 2.048 MHz and need not be synchronous. For best trans-

mission performance, however, MCLK $_{\rm R}$ should be synchronous with MCLK $_{\rm X}$, which is easily achieved by applying only static logic levels to the MCLK $_{\rm R}$ /PDN pin. This will automatically connect MCLK $_{\rm X}$ to all internal MCLK $_{\rm R}$ functions (see Pin Description). For 1.544 MHz operation, the device automatically compensates for the 193rd clock pulse each frame. FS $_{\rm X}$ starts each encoding cycle and must be synchronous with MCLK $_{\rm X}$ and BCLK $_{\rm X}$. FS $_{\rm R}$ starts each decoding cycle and must be synchronous with BCLK $_{\rm R}$. BCLK $_{\rm R}$ must be a clock, the logic levels shown in Table I are not valid in asynchronous mode. BCLK $_{\rm X}$ and BCLK $_{\rm R}$ may operate from 64 kHz to 2.048 MHz.

SHORT FRAME SYNC OPERATION

The COMBO can utilize either a short frame sync pulse or a long frame sync pulse. Upon power initialization, the device assumes a short frame mode. In this mode, both frame sync pulses, FS_X and FS_R , must be one bit clock period long, with timing relationships specified in $\mathit{Figure 2}$. With FS_X high during a falling edge of BCLK_X, the next rising edge of BCLK_X enables the D_X TRI-STATE output buffer, which will output the sign bit. The following seven rising edges clock out the remaining seven bits, and the next falling edge disables the D_X output. With FS_R high during a falling edge of BCLK_R (BCLK_X in synchronous mode), the next falling edge of BCLK_R latches in the sign bit. The following seven falling edges latch in the seven remaining bits. All devices may utilize the short frame sync pulse in synchronous or asynchronous operating mode.

LONG FRAME SYNC OPERATION

To use the long frame mode, both the frame sync pulses, FS_X and FS_R, must be three or more bit clock periods long, with timing relationships specified in Figure 3. Based on the transmit frame sync, FS_X , the COMBO will sense whether short or long frame sync pulses are being used. For 64 kHz operation, the frame sync pulse must be kept low for a minimum of 160 ns. The D_X TRI-STATE output buffer is enabled with the rising edge of FS_X or the rising edge of BCLK_X, whichever comes later, and the first bit clocked out is the sign bit. The following seven BCLKX rising edges clock out the remaining seven bits. The DX output is disabled by the falling BCLKX edge following the eighth rising edge, or by FS_X going low, whichever comes later. A rising edge on the receive frame sync pulse, FSR, will cause the PCM data at D_R to be latched in on the next eight falling edges of BCLK_R(BCLK_X in synchronous mode). All devices may utilize the long frame sync pulse in synchronous or asynchronous mode.

TRANSMIT SECTION

The transmit section input is an operational amplifier with provision for gain adjustment using two external resistors, see *Figure 4*. The low noise and wide bandwidth allow gains in excess of 20 dB across the audio passband to be realized. The op amp drives a unity-gain filter consisting of RC active pre-filter, followed by an eighth order switched-capacitor bandpass filter clocked at 256 kHz. The output of this filter directly drives the encoder sample-and-hold circuit. The A/D is of companding type according to A-law coding conventions. A precision voltage reference is trimmed in manufacturing to provide an input overload (t_{MAX}) of nominally 2.5V peak (see table of Transmission Characteristics).

Functional Description (Continued)

The FS $_{X}$ frame sync pulse controls the sampling of the filter output, and then the successive-approximation encoding cycle begins. The 8-bit code is then loaded into a buffer and shifted out through D $_{X}$ at the next FS $_{X}$ pulse. The total encoding delay will be approximately 165 μ s (due to the transmit filter) plus 125 μ s (due to encoding delay), which totals 290 μ s. Any offset voltage due to the filters or comparator is cancelled by sign bit integration.

RECEIVE SECTION

The receive section consists of an expanding DAC which drives a fifth order switched-capacitor low pass filter clocked at 256 kHz. The decoder is A-law and the 5th order low pass filter corrects for the sin x/x attenuation due to the 8 kHz sample/hold. The filter is then followed by a 2nd order RC active post-filter with its output at VFRO. The receive section is unity-gain, but gain can be added by using the power amplifiers. Upon the occurrence of FSR, the data at the DR input is clocked in on the falling edge of the next eight BCLKR (BCLKx) periods. At the end of the decoder time slot, the decoding cycle begins, and 10 μs later the decoder DAC output is updated. The total decoder delay is \sim 10 μs (decoder update) plus 110 μs (filter delay) plus 62.5 μs (½ frame), which gives approximately 180 μs .

RECEIVE POWER AMPLIFIERS

Two inverting mode power amplifiers are provided for directly driving a matched line interface transformer. The gain of the first power amplifier can be adjusted to boost the $\pm 2.5 V$ peak output signal from the receive filter up to $\pm 3.3 V$ peak into an unbalanced 300Ω load, or $\pm 4.0 V$ into an unbalanced 15 $\rm k\Omega$ load. The second power amplifier is internally connected in unity-gain inverting mode to give 6 dB of signal gain for balanced loads.

Maximum power transfer to a 600 Ω subscriber line termination is obtained by differentially driving a balanced transformer with a $\sqrt{2}$:1 turns ratio, as shown in *Figure 4*. A total peak power of 15.6 dBm can be delivered to the load plus termination.

ENCODING FORMAT AT D_X OUTPUT

	TP3069 A-Law (Includes Even Bit Inversion)							
V _{IN} = +Full-Scale	1	0	1	0	1	0	1	0
$V_{IN} = +$ Full-Scale $V_{IN} = 0V$	∫1	1	0	1	0	1	0	1
	lo	1	0	1	0	1	0	1
$V_{IN} = -Full-Scale$	0	0	1	0	1	0	1	0

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 V_{CC} to GNDA V_{BB} to GNDA -7V Voltage at any Analog Input

or Output $V_{\mbox{\footnotesize CC}}\!+\!0.3\mbox{\footnotesize V}$ to $V_{\mbox{\footnotesize BB}}\!-\!0.3\mbox{\footnotesize V}$ Voltage at any Digital Input

or Output $V_{\mbox{\footnotesize CC}}\!+\!0.3\mbox{\footnotesize V}$ to GNDA $-\,0.3\mbox{\footnotesize V}$ Operating Temperature Range -25°C to $+125^{\circ}\text{C}$ Storage Temperature Range -65°C to $+150^{\circ}\text{C}$ Lead Temp. (Soldering, 10 sec.) 300°C ESD (Human Body Model) J 1000V ESD (Human Body Model) N 1500V Latch-Up Immunity on Any Pin 100 mA

Electrical Characteristics Unless otherwise noted, limits printed in **BOLD** characters are guaranteed for $V_{CC} = +5.0V \pm 5\%$, $V_{BB} = -5.0V \pm 5\%$; $T_A = 0^{\circ}C$ to $70^{\circ}C$ by correlation with 100% electrical testing at $T_A = 25^{\circ}C$. All other limits are assured by correlation with other production tests and/or product design and characterization. All signals referenced to GNDA. Typicals specified at $V_{CC}=+5.0V,\,V_{BB}=-5.0V,\,T_{A}=25^{\circ}C.$

Symbol	Parameter	Conditions	Min	Тур	Max	Units
POWER I	DISSIPATION (ALL DEVICES)					
I _{CC} 0	Power-Down Current	(Note †)		0.5	1.5	mA
I _{BB} 0	Power-Down Current	(Note †)		0.05	0.3	mA
I _{CC} 1	Active Current	VPI=0V; VF _R O, VPO+ and VPO- unloaded		7.0	10.0	mA
I _{BB} 1	Active Current	VPI=0V; VF _R O, VPO+ and VPO- unloaded		7.0	10.0	mA
DIGITAL	INTERFACE					
V _{IL}	Input Low Voltage				0.6	٧
V _{IH}	Input High Voltage		2.2			٧
V _{OL}	Output Low Voltage	D_{X} , $I_{L} = 3.2 \text{ mA}$ $\overline{TS_{X}}$, $I_{L} = 3.2 \text{ mA}$, Open Drain			0.4 0.4	V V
V _{OH}	Output High Voltage	D_X , $I_H = -3.2 \text{ mA}$	2.4			V
I _{IL}	Input Low Current	GNDA≤V _{IN} ≤V _{IL} , All Digital Inputs	-10		10	μΑ
I _{IH}	Input High Current	V _{IH} ≤ V _{IN} ≤ V _{CC}	-10		10	μΑ
l _{OZ}	Output Current in High Impedance State (TRI-STATE)	D_X , $GNDA \le V_O \le V_{CC}$	-10		10	μΑ

Note †: I_{CC0} and I_{BB0} are measured after first achieving a power-up state.

Electrical Characteristics (Continued)

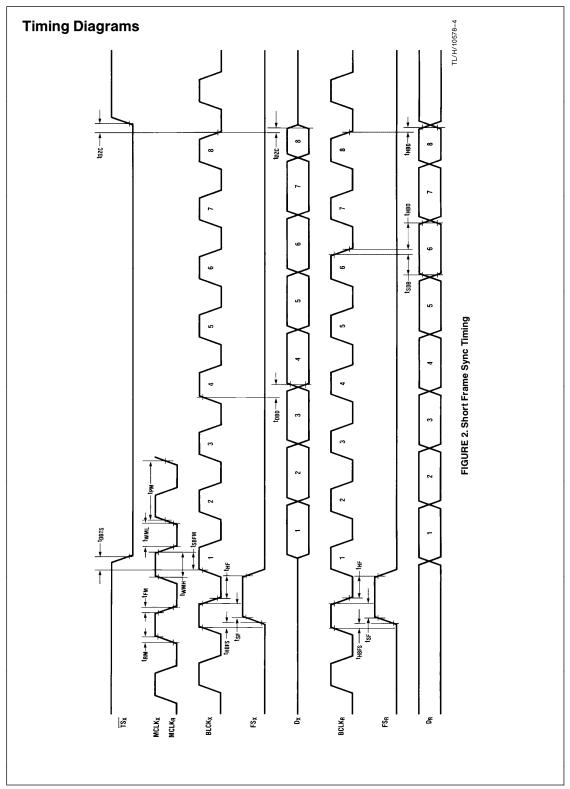
Unless otherwise noted, limits printed in **BOLD** characters are guaranteed for $V_{CC} = +5.0V \pm 5\%$, $V_{BB} = -5.0V \pm 5\%$; $T_A = 0^{\circ}C$ to 70°C by correlation with 100% electrical testing at $T_A = 25^{\circ}C$. All other limits are assured by correlation with other production tests and/or product design and characterization. All signals referenced to GNDA. Typicals specified at $V_{CC} = +5.0V$, $V_{BB} = -5.0V$, $V_{AB} = -5.0V$, V_{AB}

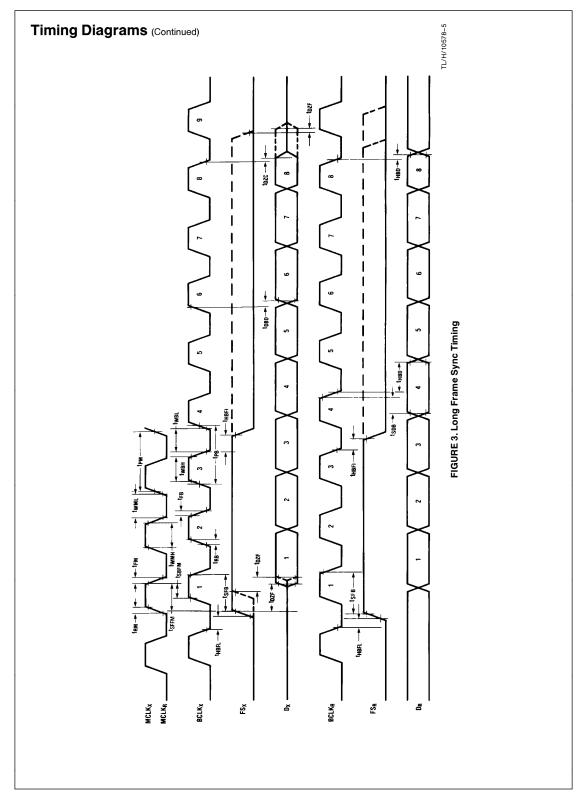
Symbol	Parameter	Conditions	Min	Тур	Max	Units
ANALOG II	NTERFACE WITH TRANSMIT INPU	T AMPLIFIER (ALL DEVICES)		•		•
I _I XA	Input Leakage Current	$-2.5V \le V \le +2.5V$, VF _X I + or VF _X I -	-200		200	nA
R _I XA	Input Resistance	$-2.5V \le V \le +2.5V$, VF _X I + or VF _X I -	10			МΩ
R _O XA	Output Resistance	Closed Loop, Unity Gain		1	3	Ω
R _L XA	Load Resistance	GS _X	10			kΩ
C _L XA	Load Capacitance	GS _X			50	pF
V _O XA	Output Dynamic Range	GS _X , R _L ≥10 kΩ	-2.8		+ 2.8	V
A _V XA	Voltage Gain	VF _X I ⁺ to GS _X	5000			V/V
F _U XA	Unity-Gain Bandwidth		1	2		MHz
V _{OS} XA	Offset Voltage		-20		20	mV
V _{CM} XA	Common-Mode Voltage	CMRRXA > 60 dB	- 2.5		2.5	V
CMRRXA	Common-Mode Rejection Ratio	DC Test	60			dB
PSRRXA	Power Supply Rejection Ratio	DC Test	60			dB
ANALOG II	NTERFACE WITH RECEIVE FILTER	R (ALL DEVICES)		•		
R _O RF	Output Resistance	Pin VF _R O		1	3	Ω
R _L RF	Load Resistance	VF _R O = ±2.5V	10			kΩ
C _L RF	Load Capacitance	Connect from VF _R O to GNDA			25	pF
VOS _R O	Output DC Offset Voltage	Measure from VF _R O to GNDA	-200		200	mV
ANALOG II	NTERFACE WITH POWER AMPLIF	IERS (ALL DEVICES)				
IPI	Input Leakage Current	-1.0V≤VPI≤1.0V	-100		100	nA
RIPI	Input Resistance	-1.0V≤VPI≤1.0V	10			МΩ
VIOS	Input Offset Voltage		-25		25	mV
ROP	Output Resistance	Inverting Unity-Gain at VPO+ or VPO-		1		Ω
F _C	Unity-Gain Bandwidth	Open Loop (VPO ⁻)		400		kHz
C _L P	Load Capacitance				100	pF
GA _P +	Gain from VPO - to VPO +	$R_L = 600\Omega \text{ VPO}^+ \text{ to VPO}^-$ Level at $VPO^- = 1.77 \text{ Vrms}$		-1		V/V
PSRR _P	Power Supply Rejection of V _{CC} or V _{BB}	VPO - Connected to VPI 0 kHz - 4 kHz 4 kHz - 50 kHz	60 36			dB dB
R _L P	Load Resistance	Connect from VPO+ to VPO-	600			Ω

Timing Specifications

Unless otherwise noted, limits printed in **BOLD** characters are guaranteed for $V_{CC} = +5.0V \pm 5\%$, $V_{BB} = -5.0V \pm 5\%$, $T_A = 0^{\circ}C$ to $70^{\circ}C$ by correlation with 100% electrical testing at $T_A = 25^{\circ}C$. All other limits are assured by correlation with other production tests and/or product design and characterization. All signals are referenced to GNDA. Typicals specified at $V_{CC} = +5.0V$, $V_{BB} = -5.0V$, $V_{AB} = -5.0V$

Symbol	Parameter	Conditions	Min	Тур	Max	Units
1/t _{PM}	Frequency of Master Clock	$MCLK_X$ and $MCLK_B$		1.536 1.544 2.048		MHz MHz MHz
t _{RM}	Rise Time of Master Clock	MCLK _X and MCLK _B		2.040	50	ns
t _{FM}	Fall Time of Master Clock	MCLK _X and MCLK _B			50	ns
t _{PB}	Period of Bit Clock	MOLITY WINDLING	485	488	15725	ns
t _{RB}	Rise Time of Bit Clock	BCLK _X and BCLK _R			50	ns
t _{FB}	Fall Time of Bit Clock	BCLK _X and BCLK _B			50	ns
t _{WMH}	Width of Master Clock High	MCLK _X and MCLK _R	160			ns
t _{WML}	Width of Master Clock Low	MCLK _X and MCLK _R	160			ns
t _{SBFM}	Set-Up Time from BCLK _X High to MCLK _X Falling Edge	First Bit Clock after the Leading Edge of FS _X	100			ns
t _{WBH}	Width of Bit Clock High		160			ns
t _{WBL}	Width of Bit Clock Low		160			ns
t _{HBFL}	Holding Time from Bit Clock Low to Frame Sync	Long Frame Only	0			ns
t _{HBFS}	Holding Time from Bit Clock High to Frame Sync	Short Frame Only	0			ns
t _{SFB}	Set-Up Time for Frame Sync to Bit Clock Low	Long Frame Only	80			ns
t _{DBD}	Delay Time from BCLK _X High to Data Valid	Load = 150 pF plus 2 LSTTL Loads	0		180	ns
t _{DBTS}	Delay Time to $\overline{TS_X}$ Low	Load = 150 pF plus 2 LSTTL Loads			140	ns
t _{DZC}	Delay Time from BCLK _X Low to Data Output Disabled		50		165	ns
t _{DZF}	Delay Time to Valid Data from FS_X or $BCLK_X$, Whichever Comes Later	C_L =0 pF to 150 pF	20		165	ns
t _{SDB}	Set-Up Time from D_R Valid to $BCLK_{R/X}$ Low		50			ns
t _{HBD}	Hold Time from $\operatorname{BCLK}_{R/X}$ Low to D_R Invalid		50			ns
t _{SF}	Set-Up Time from $FS_{X/R}$ to $BCLK_{X/R}$ Low	Short Frame Sync Pulse (1 Bit Clock Period Long)	50			ns
t _{HF}	Hold Time from $BCLK_{X/R}$ Low to $FS_{X/R}$ Low	Short Frame Sync Pulse (1 Bit Clock Period Long)	100			ns
t _{HBFI}	Hold Time from 3rd Period of Bit Clock Low to Frame Sync (FS _X or FS _R)	Long Frame Sync Pulse (from 3 to 8 Bit Clock Periods Long)	100			ns
t _{WFL}	Minimum Width of the Frame Sync Pulse (Low Level)	64k Bit/s Operating Mode	160			ns
tSFFM	Set-Up Time from FS _X High to MCLK _X Falling Edge	Long Frame Only	100			ns





Transmission Characteristics

Unless otherwise noted, limits printed in **BOLD** characters are guaranteed for $V_{CC}=+5.0V\pm5\%$, $V_{BB}=-5.0V\pm5\%$; $T_A=0^{\circ}C$ to 70°C by correlation with 100% electrical testing at $T_A=25^{\circ}C$. All other limits are assured by correlation with other production tests and/or product design and characterization. GNDA = 0V, f = 1.02 kHz, $V_{IN}=0$ dbm0, transmit input amplifier connected for unity gain non-inverting. Typicals specified at $V_{CC}=+5.0V$, $V_{BB}=-5.0V$, $T_A=25^{\circ}C$.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
AMPLITU	JDE RESPONSE					
	Absolute Levels (Definition of nominal gain)	Nominal 0 dBm0 Level is 4 dBm (600Ω) 0 dBm0		1.2276		Vrms
t _{MAX}	Virtual Decision Value Defined per CCITT Rec. G711	Max Transmit Overload Level TP3069 (3.14 dBm0)		2.492		V _{PK}
G _{XA}	Transmit Gain, Absolute	$T_A = 25$ °C, $V_{CC} = 5V$, $V_{BB} = -5V$	-0.15		0.15	dB
G _{XR}	Transmit Gain, Relative to G _{XA}	f=16 Hz f=50 Hz f=60 Hz f=200 Hz f=300 Hz-3000 Hz f=3300 Hz f=3400 Hz f=4000 Hz f=4600 Hz and Up, Measure Response from 0 Hz to 4000 Hz	-1.8 -0.15 -0.35 -0.7		-40 -30 -26 -0.1 0.15 0.05 0 -14 -32	dB dB dB dB dB dB dB
G _{XAT}	Absolute Transmit Gain Variation with Temperature	Relative to G _{XA}	-0.1		0.1	dB
G_XAV	Absolute Transmit Gain Variation with Supply Voltage	Relative to G _{XA}	-0.05		0.05	dB
G _{XRL}	Transmit Gain Variations with Level	Sinusoidal Test Method Reference Level = -10 dBm0 VF_X + = $-40 \text{ dBm0 to } + 3 \text{ dBm0}$ VF_X + = $-50 \text{ dBm0 to } -40 \text{ dBm0}$ VF_X + = $-55 \text{ dBm0 to } -50 \text{ dBm0}$	- 0.2 - 0.4 - 1.2		0.2 0.4 1.2	dB dB dB
G _{RA}	Receive Gain, Absolute	T _A =25°C, V _{CC} =5V, V _{BB} =-5V Input=Digital Code Sequence for 0 dBm0 Signal	-0.15		0.15	dB
G _{RR}	Receive Gain, Relative to G _{RA}	f=0 Hz to 3000 Hz f=3300 Hz f=3400 Hz f=4000 Hz	-0.15 -0.35 -0.7		0.15 0.05 0 -14	dB dB dB dB
G _{RAT}	Absolute Receive Gain Variation with Temperature	Relative to G _{RA}	-0.1		0.1	dB
G _{RAV}	Absolute Receive Gain Variation with Supply Voltage	Relative to G _{RA}	-0.05		0.05	dB
G _{RRL}	Receive Gain Variations with Level	Sinusoidal Test Method; Reference Input PCM Code Corresponds to an Ideally Encoded — 10 dBm0 Signal PCM Level = -40 dBm0 to +3 dBm0 PCM Level = -50 dBm0 to -40 dBm0 PCM Level = -55 dBm0 to -50 dBm0	- 0.2 - 0.4 - 1.2		0.2 0.4 1.2	dB dB dB
V _{RO}	Receive Filter Output at VF _R O	$RL = 10 \text{ k}\Omega$	-2.5		2.5	V

Transmission Characteristics (Continued)

Unless otherwise noted, limits printed in **BOLD** characters are guaranteed for $V_{CC} = +5.0V \pm 5\%$, $V_{BB} = -5.0V \pm 5\%$; $T_A = 0^{\circ}C$ to 70°C by correlation with 100% electrical testing at $T_A = 25^{\circ}C$. All other limits are assured by correlation with other production tests and/or product design and characterization. GNDA = 0V, f = 1.02 kHz, $V_{IN} = 0$ dbm0, transmit input amplifier connected for unity gain non-inverting. Typicals specified at $V_{CC} = +5.0V$, $V_{BB} = -5.0V$, $T_A = 25^{\circ}C$.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
ENVELOP	PE DELAY DISTORTION WITH FREQU	JENCY				
D _{XA}	Transmit Delay, Absolute	f=1600 Hz		290	315	μs
D _{XR}	Transmit Delay, Relative to D _{XA}	f=500 Hz-600 Hz f=600 Hz-800 Hz f=800 Hz-1000 Hz f=1000 Hz-1600 Hz f=1600 Hz-2600 Hz f=2600 Hz-2800 Hz		195 120 50 20 55 80	220 145 75 40 75 105	րs րs րs րs րs
		f=2800 Hz-3000 Hz		130	155	μs
D_{RA}	Receive Delay, Absolute	f=1600 Hz		180	200	μs
D _{RR}	Receive Delay, Relative to D _{RA}	f=500 Hz -1000 Hz f=1000 Hz -1600 Hz f=1600 Hz -2600 Hz f=2600 Hz -2800 Hz f=2800 Hz -3000 Hz	-40 -30	-25 -20 70 100 145	90 125 175	μs μs μs μs μs
NOISE			I			•
N _{XP}	Transmit Noise, Psophometric Weighted	TP3069 (Note 1)		-74	-67	dBm0
N _{RP}	Receive Noise, Psophometric Weighted	PCM Code Equals Positive Zero TP3069		-82	-79	dBm0
N _{RS}	Noise, Single Frequency	$f=0$ kHz to 100 kHz, Loop Around Measurement, $VF_XI^+=0$ Vrms			-53	dBm0
PPSR _X	Positive Power Supply Rejection, Transmit	$V_{CC} = 5.0 V_{DC} + 100 \text{ mVrms}$ f = 0 kHz - 50 kHz (Note 2)	40			dBC
NPSRX	Negative Power Supply Rejection, Transmit	$V_{BB} = -5.0 V_{DC} + 100 \text{ mVrms}$ f = 0 kHz -50 kHz (Note 2)	40			dBC
PPSR _R	Positive Power Supply Rejection, Receive	PCM Code Equals Positive Zero $V_{CC} = 5.0 \ V_{DC} + 100 \ mVrms$ $Measure \ VF_{RO}$ $f = 0 \ Hz - 4000 \ Hz$ $f = 4 \ kHz - 50 \ kHz$	38 25			dBC dB
NPSR _R	Negative Power Supply Rejection, Receive	PCM Code Equals Positive Zero $V_{BB} = -5.0 \ V_{DC} + 100 \ mVrms$ Measure VF_{RO} $f = 0 \ Hz - 4000 \ Hz$ $f = 4 \ kHz - 25 \ kHz$ $f = 25 \ kHz - 50 \ kHz$	40 40 36			dBC dB dB
SOS	Spurious Out-of-Band Signals at the Channel Output	0 dBm0, 300 Hz – 3400 Hz Input PCM Code Applied at DR Measure Individual Image Signals at VF _R O 4600 Hz-7600 Hz 7600 Hz-8400 Hz 8400 Hz-100,000 Hz			- 32 -40 - 32	dB dB dB

Transmission Characteristics (Continued)

Unless otherwise noted, limits printed in **BOLD** characters are guaranteed for $V_{CC} = +5.0V \pm 5\%$, $V_{BB} = -5.0V \pm 5\%$; $T_A = 0^{\circ}C$ to 70°C by correlation with 100% electrical testing at $T_A = 25^{\circ}C$. All other limits are assured by correlation with other production tests and/or product design and characterization. GNDA = 0V, f = 1.02 kHz, $V_{IN} = 0$ dbm0, transmit input amplifier connected for unity gain non-inverting. Typicals specified at $V_{CC} = +5.0V$, $V_{BB} = -5.0V$, $T_A = 25^{\circ}C$.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
DISTORT	ION					
STD _X , STD _R	Signal to Total Distortion Transmit or Receive Half-Channel	Sinusoidal Test Method (Note 3) Level = 3.0 dBm0 = 0 dBm0 to -30 dBm0 = -40 dBm0 XMT RCV = -55 dBm0 XMT RCV	33 36 29 30 14 15			dBC dBC dBC dBC dBC
SFD _X	Single Frequency Distortion, Transmit				-46	dB
SFD _R	Single Frequency Distortion, Receive				-46	dB
IMD	Intermodulation Distortion	Loop Around Measurement, $VF_XI^+ = -4$ dBm0 to -21 dBm0, Two Frequencies in the Range 300 Hz -3400 Hz			-41	dB
CROSST	ALK					
CT _{X-R}	Transmit to Receive Crosstalk	f=300 Hz-3000 Hz D _R =Quiet PCM Code		-90	-75	dB
CT _{R-X}	Receive to Transmit Crosstalk	f=300 Hz-3000 Hz, VF _X I=0V (Note 2)		-90	-70	dB
POWER A	AMPLIFIERS					
V _O PA	Maximum 0 dBm0 Level (Better than ±0.1 dB Linearity over the Range -10 dBm0 to +3 dBm0)	Balanced Load, R _L Connected Between VPO+ and VPO $R_L = 600\Omega$ $R_L = 1200\Omega$	3.3 3.5			Vrms Vrms
S/D _P	Signal/Distortion	$R_L = 600\Omega$	50			dB

Note 1: Measured by extrapolation from the distortion test result at $-50\ \mbox{dBm0}.$

Note 2: PPSR χ , NPSR χ , and CT $_{R-\chi}$ are measured with a -50 dBm0 activation signal applied to VF χ I $^+$.

Note 3: TP3069 is measured using psophometric weighted filter.

Applications Information

POWER SUPPLIES

While the pins of the TP3060 family are well protected against electrical misuse, it is recommended that the standard CMOS practice be followed, ensuring that ground is connected to the device before any other connections are made. In applications where the printed circuit board may be plugged into a "hot" socket with power and clocks already present, an extra long ground pin in the connector should be used

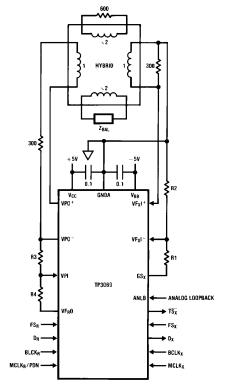
All ground connections to each device should meet at a common point as close as possible to the GNDA pin. This

minimizes the interaction of ground return currents flowing through a common bus impedance. 0.1 μF supply decoupling capacitors should be connected from this common ground point to V_{CC} and $V_{BB},$ as close to the device as possible.

For best performance, the ground point of each CODEC/FILTER on a card should be connected to a common card ground in "STAR" formation, rather than via a ground bus. This common ground point should be decoupled to V_{CC} and V_{BB} with 10 μF capacitors.

Note: See Application Note 370 for further details

Typical Asynchronous Application



TL/H/10578-6

Note 1: Transmit gain
$$=20 \times log \left(\frac{R1+R2}{R2}\right)$$
, $(R1+R2) \ge 10 \ k\Omega$
Note 2: Receive gain $=20 \times log \left(\frac{2 \times R3}{R4}\right)$, $R4 \ge 10 \ k\Omega$

FIGURE 4

Definitions and Timing Conventions

DEFINITIONS

VOL

 $V_{\mbox{\scriptsize IH}}$ is the d.c. input level above which V_{IH} an input level is guaranteed to appear

> as a logical one. This parameter is to be measured by performing a functional test at reduced clock speeds and nominal timing, (i.e. not minimum setup and hold times or output strobes), with the high level of all driving signals set to VIH and maximum supply voltages applied to

 V_{IL} VIL is the d.c. input level below which

an input level is guaranteed to appear as a logical zero to the device. This parameter is measured in the same manner as V_{IH} but with all driving signal low levels set to V_{IL} and minimum supply voltages applied to

the device.

 V_{OH} VOH is the minimum d.c. output level

to which an output placed in a logical one state will converge when loaded at the maximum specified load current. V_{OL} is the maximum d.c. output level

to which an output placed in a logical zero state will converge when loaded at the maximum specified load current.

The threshold region is the range of Threshold Region input voltages between VIL and VIH.

Valid Signal A signal is Valid if it is in one of the valid logic states, (i.e. above VIH or

below VIL). In timing specifiations, a signal is deemed valid at the instant it

enters a valid state.

Invalid Signal A signal is Invalid if it is not in a valid

logic state, i.e. when it is in in the threshold region between VIL and VIH. In timing specifications, a signal is deemed Invalid at the instant it enters

the threshold region.

TIMING CONVENTIONS

For the purposes of this timing specification, the following

conventions apply:

Input Signals All input signals may be characterized

as: $V_L = 0.4V$, $V_H = 2.4V$, $t_R < 10$ ns,

t⊏ < 10 ns.

Period The period of clock signal is designated as t_{Pxx} where xx

represents the mnemonic of the clock

signal being specified.

Rise times are designated as t_{Ryy}, Rise Time

where yy represents a mnemonic of the signal whose rise time is being specified. t_{Ryy} is measured from \tilde{V}_{IL} to

 V_{IH} .

Fall times are designated as t_{Fyy} , where yy represents a mnemonic of Fall Time

the signal whose fall time is being specified. t_{FVV} is measured from V_{IH} to

Pulse Width High The high pulse width is designated as

t_{WzzH}, where zz represents the mnemonic of the input or output signal whose pulse width is being specified. High pulse widths are measured from

V_{IH} to V_{IH}.

Pulse Width Low The low pulse width is designated as

twzzL, where zz represents the mnemonic of the input or output signal whose pulse width is being specified. Low pulse widths are measured from

VII to VII.

Setup times are designated as t_{Swwxx}, Setup Time

where ww represents the mnemonic of the input signal whose setup time is being specified relative to a clock or strobe input represented by mnemonic xx. Setup times are measured from the

ww Valid to xx Invalid.

Hold times are designated as t_{Hxxww} Hold Time where ww represents the mnemonic of

the input signal whose hold time is being specified relative to a clock or strobe input represented by mnemonic xx. Hold times are measured from xx

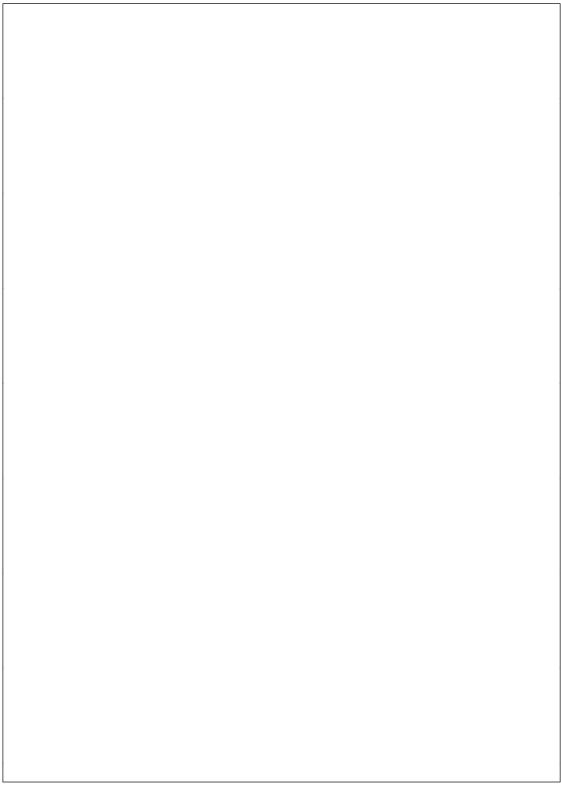
Valid to ww Invalid.

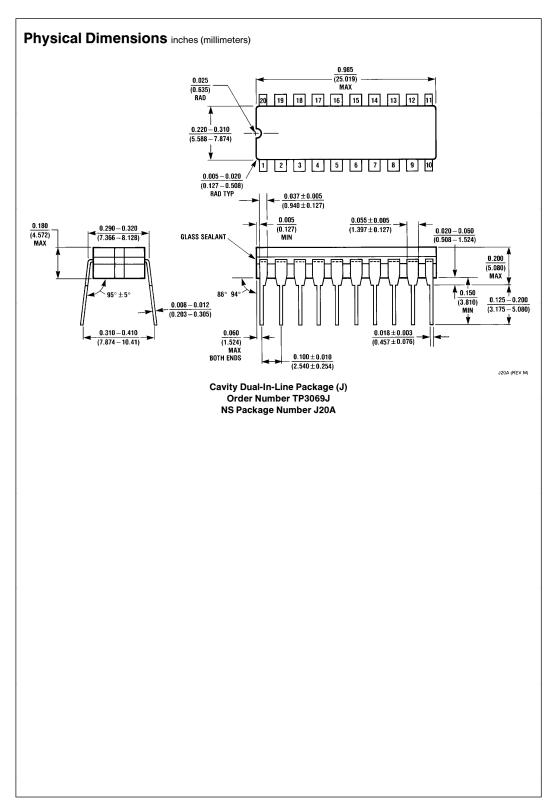
Delay times are designated as t_{Dxxyy} **Delay Time**

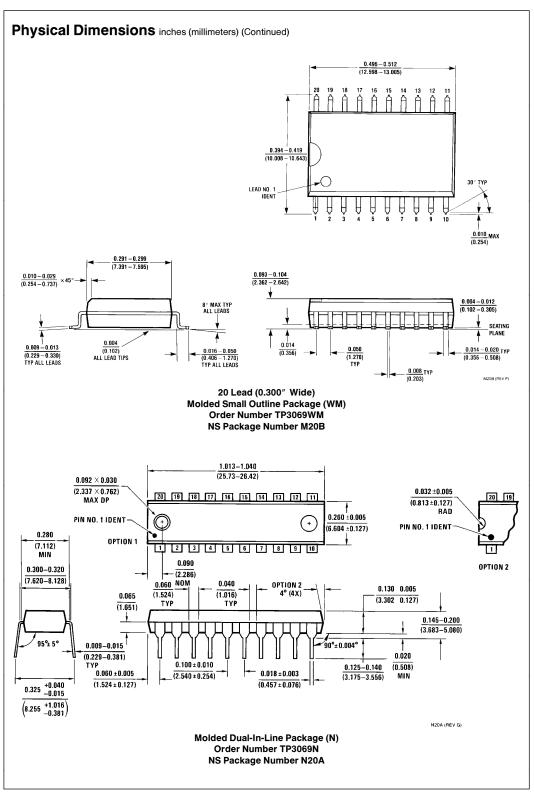
Hi to Low, where xx represents the mnemonic of the input reference signal and yy represents the mnemonic of the output signal whose timing is being specified relative to xx. The mnemonic may optionally be terminated by an H or L to specify the high going or low going transition of the output signal. Maximum delay times are measured from xx Valid to yy Valid. Minimum delay times are measured from xx Valid to yy Invalid.

This parameter is tested under the load conditions specified in the Conditions column of the Timing Specifications section of this data

sheet.

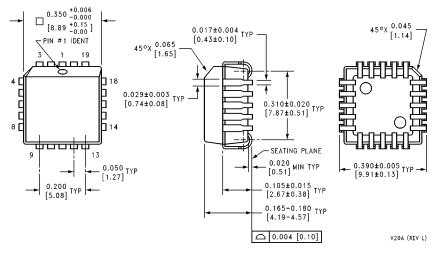






Physical Dimensions inches (millimeters) (Continued)

Lit. # 113976



Plastic Chip Carrier (V) **Order Number TP3069V** NS Package Number V20A

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